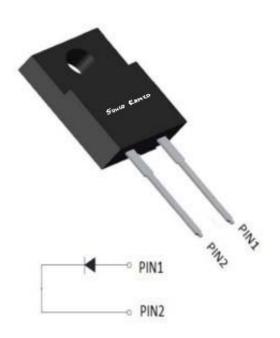


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: ITO-220AC

Molding compound meets UL 94 V-0 flammability

rating,

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR5200F	
Device marking code			MBR5200F	
Repetitive Peak Reverse Voltage	V_{RRM}	V	200	
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25℃	Io	А	5	
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25℃	I _{FSM}	А	120	
Current Squared Time @1ms≤t≤8.3ms Tj=25℃,	l²t	A ² s	60	
Storage Temperature	T_{stg}	$^{\circ}$ C	-55 ~ + 175	
Junction Temperature	Tj	°C	-55 ~ + 175	

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR5200F
Maximum instantaneous forward voltage drop per diode	V_{FM}	٧	I _{FM} =5.0A	0.9
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	V _{RM} =V _{RRM} Ta=25°C	0.1
	I _{RRM2}		V _{RM} =V _{RRM} Ta=125℃	20

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS



■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PA	RAMETER	SYMBOL	UNIT	MBR5200F
Thermal Resistance	Between junction and case	R _{θJ-C}	°C/W	4.0

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR5200F	Approximate 1.6	50	1000	5000	Tube

■Characteristics (Typical)

FIG1:lo -Tc Curve Average Forward Output Current (A) 7.0 6.0 5.0 4.0 TC measure point 3.0 2.0 1.0

100

Case Temperature (°C)

150

200

50

FIG2:Surge Forward Current Capability

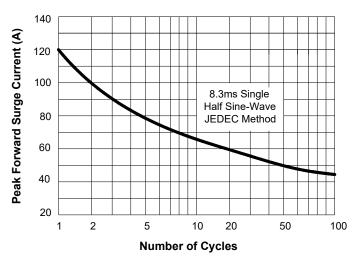
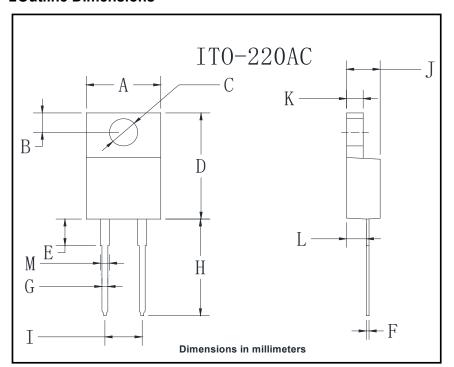


FIG3: Forward Voltage 60 40 Instantaneous Forward Current (A) 20 10 5.0 1.0 0.5 0.2 Ta=25°C 0.1 0 0.7 0.8 1.0 1.1 0.4 0.5 0.6 0.9 Instantaneous Forward Voltage (V)

FIG.4: Instantaneous Reverse Characteristics 100 Instantaneous Reverse Current (mA) 10 Tj=125℃ 1.0 0.1 Tj=25℃ 0.01 0.001 100 Percent of Rated Peak Reverse Voltage (%)



■Outline Dimensions



ITO-220AC						
Dim	Min	Max				
Α	9.8	10.2				
В	2.25	2.75				
С	2.95	3.45				
D	14.75	15.25				
Е	3.5	4.1				
F	0.45	0.75				
G	0.45	0.75				
Н	13.35	14.15				
I	4.97	5.23				
J	4.3	4.8				
K	2.5	2.74				
L	2.58	2.82				
М	1.03	1.43				



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